

# SANYO Semiconductors DATA SHEET

# LA42351—5W 1-Channel AF Power Amplifier With DC Volume Control

#### Overview

LA42351 is 5W 1-channel AF power amplifier with DC volume control intended for televisions.

#### **Features**

- PO1 5W×1ch (VCC = 18V,  $R_L = 8\Omega$ , THD = 10%)
- $P_{O2}$  3W×1ch ( $V_{CC}$  = 14V,  $R_L$  = 8 $\Omega$ , THD = 10%)
- Built-in DC Volume Control.
- Built-in Standby function.
- Built-in overheat protection.

LA42000 series is power IC which made Pin compatible possible altogether in 3 to 15W. They consist of four kinds of power ICs. (mono, stereo, mono with volume function, stereo with volume function.). They realized PCB layout communalization of an audio power block of TV. Since some external parts are different, however, the pattern design must enable sharing of the substrate.

	D -	Channel		Volume
	Po	Mono	Stereo	volume
LA42051	5W	0		
LA42052	5W		0	
LA42351	5W	0		0
LA42352	5W		0	0
LA42071	7W	0		
LA42072	7W		0	
LA42152	15W		0	

- Any and all SANYO Semiconductor Co.,Ltd. products described or contained herein are, with regard to "standard application", intended for the use as general electronics equipment (home appliances, AV equipment, communication device, office equipment, industrial equipment etc.). The products mentioned herein shall not be intended for use for any "special application" (medical equipment whose purpose is to sustain life, aerospace instrument, nuclear control device, burning appliances, transportation machine, traffic signal system, safety equipment etc.) that shall require extremely high level of reliability and can directly threaten human lives in case of failure or malfunction of the product or may cause harm to human bodies, nor shall they grant any guarantee thereof. If you should intend to use our products for applications outside the standard applications of our customer who is considering such use and/or outside the scope of our intended standard applications, please consult with us prior to the intended use. If there is no consultation or inquiry before the intended use, our customer shall be solely responsible for the use.
- Specifications of any and all SANYO Semiconductor Co.,Ltd. products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.

#### **Specifications**

#### **Absolute Maximum Ratings** at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V <sub>CC</sub> max	No signal	24	V
Allowable power dissipation	Pd max	Infinite heat sink	15	W
Maximum junction temperature	Tj max		150	°C
Thermal resistance	θјс		3	°C/W
Operating temperature	Topr		-25 to +75	°C
Storage temperature	Tstg		-40 to +150	°C

#### **Operating Conditions** at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Recommended supply voltage	VCC		18	٧
Recommended load resistance	RL		8	Ω
Allowable operating voltage range	V <sub>CC</sub> op		10 to 22	V

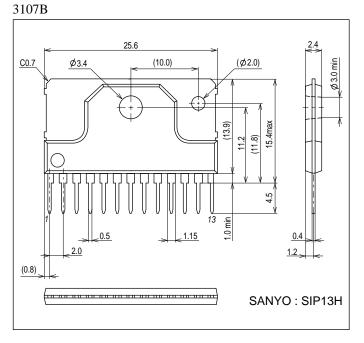
### Operating Characteristics at $Ta=25^{\circ}C,\ V_{CC}=18V,\ R_L=8\Omega,\ V_{CONT}=5V,\ f=1kHz,\ Rg=600\Omega$

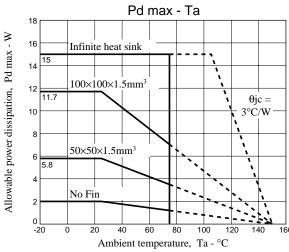
Parameter	Symbol	Conditions	Ratings			1.1-2
Parameter			min	typ	max	Unit
Standby current	ISTB	Amplifier off		0	10	μΑ
Quiescent current	<sup>I</sup> cco	$Rg = 0\Omega$ , $Volume = 0V$	15	35	70	mA
Output power	PO	THD = 10%	4	5		W
Total harmonic distortion	THD	P <sub>O</sub> = 1W		0.2	8.0	%
Voltage gain	VG	V <sub>O</sub> = 0dBm	32.5	34.5	36.5	dB
Output noise voltage	V <sub>NO</sub>	Rg = $0\Omega$ , $V_{CONT} = 0V$ , f = $20$ Hz to $20$ kHz		0.13	0.4	mVrms
Volume attenuation	ATT	$V_{IN} = 100$ mV, $V_{CONT} = 0$ V, with 1k-BPF	70	80		dB
Standby control voltage	V <sub>STB</sub> -H	Amplifier on	2.5		10	V
(The Pin 5 voltage)	V <sub>STB</sub> -L	Amplifier off	0		0.5	V
Input resistance	Ri		14	20	26	kΩ

 $*0dBm = 1mW (600\Omega) = 774.6mVrms$ 

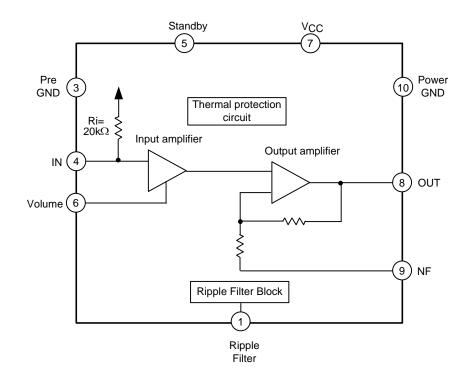
# **Package Dimensions**

unit: mm (typ)

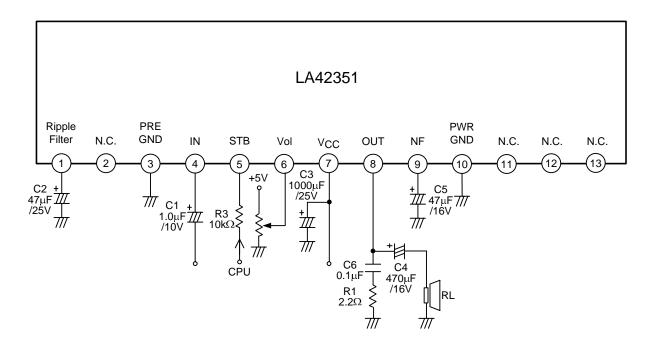




# **Block Diagram**



# **Sample Application Circuit**



# **Pin Description**

	escription	Pin Voltage		
Pin No	Symbol	At V <sub>CC</sub> = 18V	Description	Equivalent Circuit
1	RF	17.6	Ripple filter reference	$\begin{array}{c c} \hline 10k\Omega & 200\Omega \\ \hline 5.1k\Omega & 200\Omega \\ \hline M \end{array}$ $\begin{array}{c c} \hline 30k\Omega & 30k\Omega & 30k\Omega \end{array}$
4	IN	4.4	• Input pin	VCC 200Ω 20kΩ 3 4.4V
3	PRE_GND	0	Pre GND pin	
5	STB	0 to 10V (Input voltage)	Standby pin     The standby function is on when this pin at ground level	$\begin{array}{c c}  & VCC \\ \hline  & & \\ \hline  $
9	Vol	0 to 5V (Input voltage)	Control Volume	6 200Ω (M+W)
7				51kΩ ₹ ↓

Continued on next page.

Continued from preceding page.

Pin No         Symbol         Pin Voltage At V <sub>CC</sub> = 18V         Description         Equivalent Circuit           8         OUT         8.9         • Output pin         VCC           9         NF         8.8         • Negative feedback pin at Power amplifier • Connect NF capacitor           10         PWR_GND         0         • Power GND pin	Commuca	from preceding pa	450.			
8 OUT 8.9 • Output pin  9 NF 8.8 • Negative feedback pin at Power amplifier • Connect NF capacitor  9 NF 8.8 • Negative feedback pin at Power amplifier • Connect NF capacitor	Pin No Symbol			Description	Equivalent Circuit	
9 NF 8.8 • Negative feedback pin at Power amplifier • Connect NF capacitor  9 OND  10kΩ GND  VCC  VCC  270Ω  9 MM 10kΩ GND		Gyze.	At $V_{CC} = 18V$	2 cost.pub.		
amplifier • Connect NF capacitor  270Ω  9  40  GND	8	OUT		Output pin	10kΩ 8 *5.1kΩ	
10 PWR_GND 0 • Power GND pin	9	NF	8.8	amplifier	9 270Ω	
	10	PWR_GND	0	Power GND pin		

#### **Description of External parts**

- C1 : Input capacitors. A value of  $1.0\mu F$  is recommended for capacitors. Note that the low-frequency area characteristics can be adjusted by changing  $f_L$ .
- C2 : Ripple filter capacitor. A value of 47μF is recommended for capacitors. Decreasing the capacitance value excessively or removing this capacitor causes ripple to occur. However, increasing the capacitance value does not always cause ripple to reduced. Decreasing the capacitance value makes the starting time earlier.
- C3 : Power capacitor.
- : Output capacitors. A value of 470µF is recommended for capacitors.
- C5 : Feedback capacitor. A value of  $47\mu F$  is recommended for capacitors. Decreasing the capacitance value lowers the low frequency response. Increasing the capacitance value makes the starting time later.
- C6 : Oscillation blocking capacitor. Use a polyester film capacitor that is good in high frequency response and temperature characteristic.
- R1 : Resistor connected in series with oscillation blocking capacitor. Prevents phase shift attributable to the oscillation blocking capacitor so that oscillation is hard to occur.
- R3 : Standby switch current limiting resistor. A value of  $10k\Omega$  is recommended for resistance (when the applied voltage for the standby switch is 3V to 10V). This resistor cannot be removed.

#### Features of IC Inside and Usage Note

Standby function

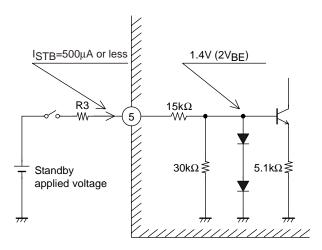
• Pin 5 is the standby switch pin. The amplifier is turned on by applying approximately 3V or more to this pin through an external resistor (R3).

$$I_{STB} = \frac{(5-2V_{BE})}{15k}$$

$$V_{BE} = \text{about } 0.7V$$

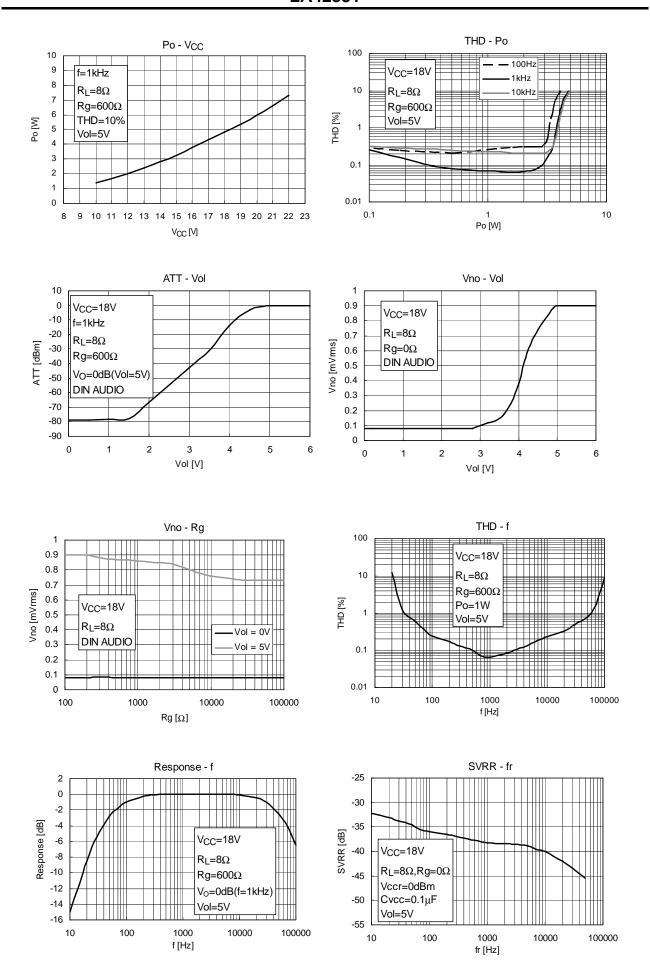
• If voltage in excess of 10V is to be applied to the standby switch, calculate the value of R3 using the following formula so that the current flowing into pin 5 is  $500\mu A$  or less:

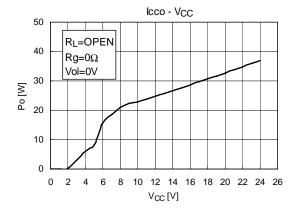
$$R3 = \frac{\text{(Applied voltage-2VBE)}}{500\mu\text{A}} \text{ -15k}\Omega$$

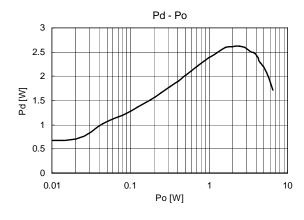


#### Protector

• In order to prevent damage or degradation which may be caused by abnormally heated IC, the LA42351 has a thermal shutdown protector. Accordingly, if the IC junction temperature (Tj) climbs to around 160°C due to inadequate heat dissipation, the thermal shutdown protector will operate to control the output gradually into attenuation.







- SANYO Semiconductor Co.,Ltd. assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all SANYO Semiconductor Co.,Ltd. products described or contained herein.
- SANYO Semiconductor Co.,Ltd. strives to supply high-quality high-reliability products, however, any and all semiconductor products fail or malfunction with some probability. It is possible that these probabilistic failures or malfunction could give rise to accidents or events that could endanger human lives, trouble that could give rise to smoke or fire, or accidents that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.
- In the event that any or all SANYO Semiconductor Co.,Ltd. products described or contained herein are controlled under any of applicable local export control laws and regulations, such products may require the export license from the authorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written consent of SANYO Semiconductor Co.,Ltd.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the SANYO Semiconductor Co.,Ltd. product that you intend to use.
- Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production.
- Upon using the technical information or products described herein, neither warranty nor license shall be granted with regard to intellectual property rights or any other rights of SANYO Semiconductor Co.,Ltd. or any third party. SANYO Semiconductor Co.,Ltd. shall not be liable for any claim or suits with regard to a third party's intellectual property rights which has resulted from the use of the technical information and products mentioned above.

This catalog provides information as of March, 2008. Specifications and information herein are subject to change without notice.